BSP51H6327XTSA1 Information

For Reference Only

Part Number	BSP51H6327XTSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN DARL 60V 1A SOT223
Package	TO-261-4, TO-261AA

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

BSP51H6327XTSA1 Specifications

Manufacturer Part Number	BSP51H6327XTSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-261-4, TO-261AA
Series	-
Transistor Type	NPN - Darlington
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	1.8V @ 1mA, 1A
Current - Collector Cutoff (Max)	10μA
DC Current Gain (hFE) (Min) @ Ic, Vce	2000 @ 500mA, 10V
Power - Max	1.5W
Frequency - Transition	200MHz
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-261-4, TO-261AA
Supplier Device Package	PG-SOT223-4
	Report errors?

BSP51H6327XTSA1 Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

BSP51H6327XTSA1 Payment Methods

BSP51H6327XTSA1 Shipping Methods

If you have any question about BSP51H6327XTSA1, please do not hesitate to contact us!
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